

Characterization of $\text{In}_2\text{O}_3:\text{Sn}/i\text{-ZnO}$ nanocrystalline thin films on polyimide substrates

N.H. Refahati^{1,2}, A.V. Karotki², A.V. Mudryi², M.V. Yakushev³

¹Department of Mechanical Engineering, Damavand Branch, Islamic Azad University, Damavand, Tehran, Iran

²Scientific-Practical Material Research Centre of the National Academy of Science of Belarus, Minsk, Belarus

³Department of Physics, Strathclyde University, Glasgow, G4 0NG, UK

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It is well known that the highly resistive zinc oxide layers with intrinsic conductivity (*i*-ZnO) are commonly introduced between the buffer CdS nanolayers (~ 30 – 50 nm) and the transparent conductive oxide layers (tin-doped indium oxide, $\text{In}_2\text{O}_3:\text{Sn}$ ~ 200 – 300 nm) in $\text{Cu}(\text{In,Ga})\text{Se}_2$ – based solar cells which usually fabricated on soda-lime glass or polyimide substrates [1,2].

In this paper we present analysis of the structural and optical properties of nanocrystalline $\text{In}_2\text{O}_3:\text{Sn}/i\text{-ZnO}$ thin films fabricated on polyimide substrates by radio frequency (RF) magnetron sputtering technique. The polyimide substrates – polyethylene terephthalate (PET) and polyethylene naphthalate (PEN) films with a thickness of about 25 μm were also investigated by luminescence, transmittance and X-ray diffraction (XRD) methods at room temperature. The X-ray patterns of $\text{In}_2\text{O}_3:\text{Sn}/i\text{-ZnO}/\text{PET}$ and $\text{In}_2\text{O}_3:\text{Sn}/i\text{-ZnO}/\text{PEN}$ heterostructures shows a preferred orientation of the $\text{In}_2\text{O}_3:\text{Sn}$ grains along the [400] direction, which is generally observed for near-stoichiometric polycrystalline films. Both heterostructures show high transmittance exceeding 50 % in the visible region of about ~ 400 – 1000 nm. The decreasing transmittance in the near-infrared region 0.5 – 1 eV is related with higher carrier concentration in $\text{In}_2\text{O}_3:\text{Sn}$ thin layers. The influence of oxygen on physical properties of $\text{In}_2\text{O}_3:\text{Sn}/i\text{-ZnO}/\text{PEN}$ and $\text{In}_2\text{O}_3:\text{Sn}/i\text{-ZnO}/\text{PET}$ heterostructures has been also discussed.

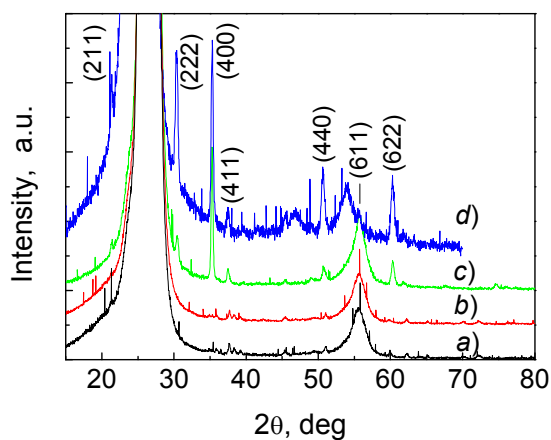


Fig.1 – XRD-pattern of polyimide and heterostructure a – PEN, b – PET, c – ITO/*i*-ZnO/PEN, d – ITO/*i*-ZnO/PET on polyimide substrate.

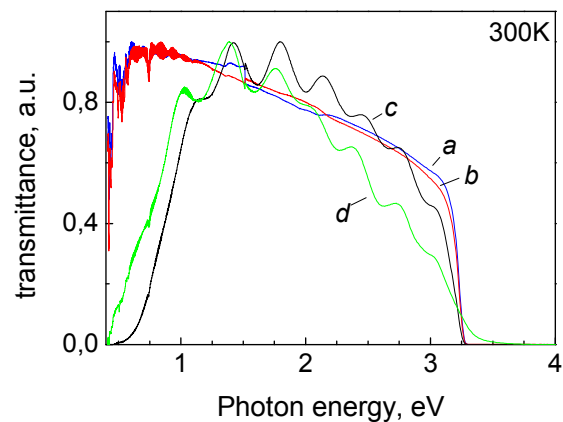


Fig.2 – Optical transmittance spectra of polyimide and heterostructure on polyimide substrate: a – PEN, b – PET, c – ITO/*i*-ZnO/PEN, d – ITO/*i*-ZnO/ PET.

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